

Features

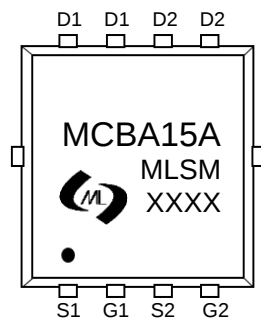
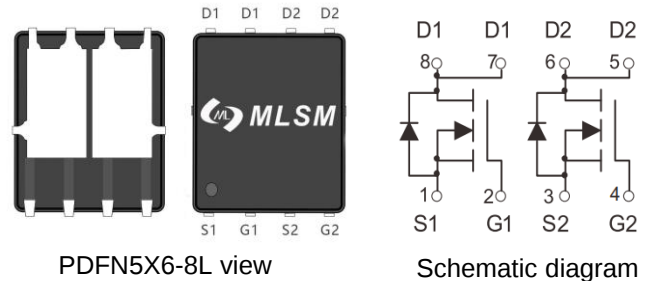
- Super high density cell design for extremely low $R_{DS(ON)}$
- Exceptional on-resistance and maximum DC current capability

Product Summary

V_{DS}	$R_{DS(ON)}$ TYP	I_D
100V	75mΩ@10V	15A
	85mΩ@4.5V	

Application

- Power Management in Note book
- DC/DC Converter
- Load Switch
- LCD Display inverter



MCBA15A : Device code
XXXX : Code

Marking and pin assignment



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
V_{DS}	Drain-Source Breakdown Voltage	100	V
V_{GS}	Gate-Source Voltage	±20	V
T_J	Maximum Junction Temperature	150	°C
T_{STG}	Storage Temperature Range	-50 to 155	°C
I_S	Diode Continuous Forward Current	15	A

Mounted on Large Heat Sink

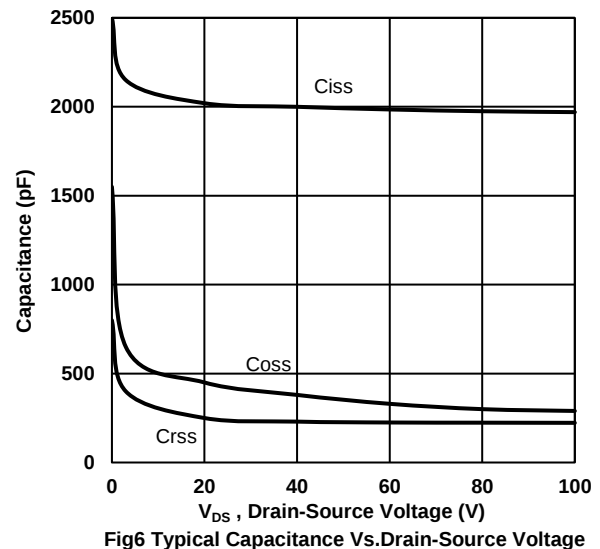
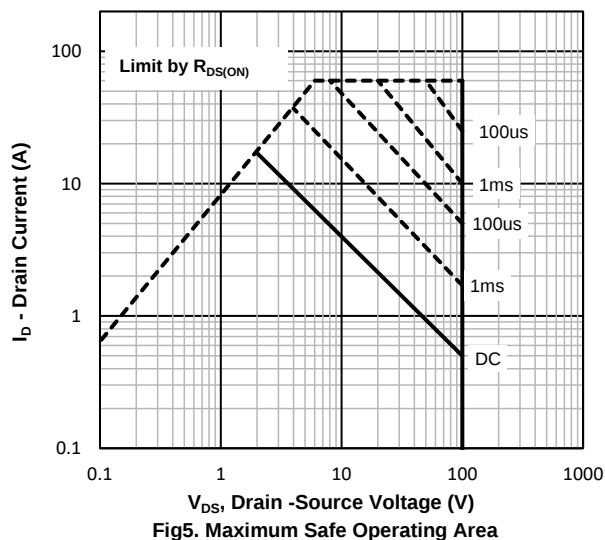
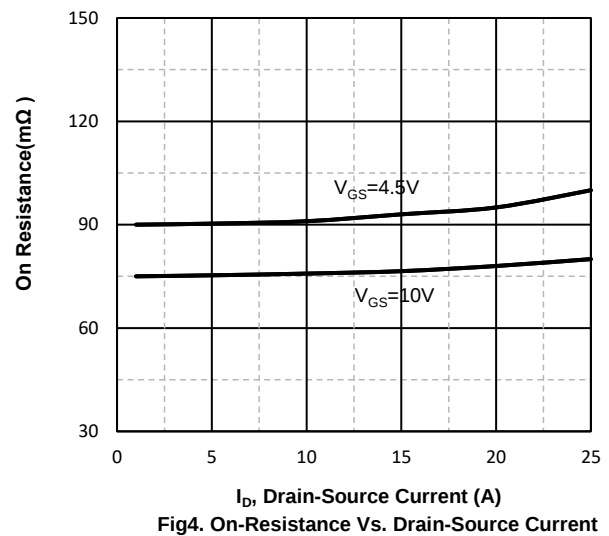
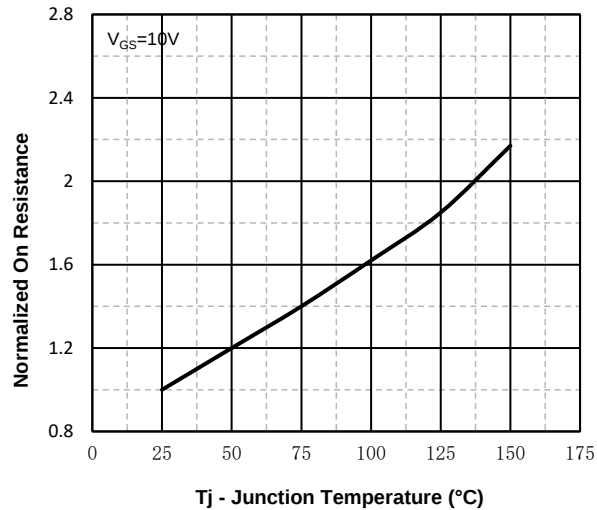
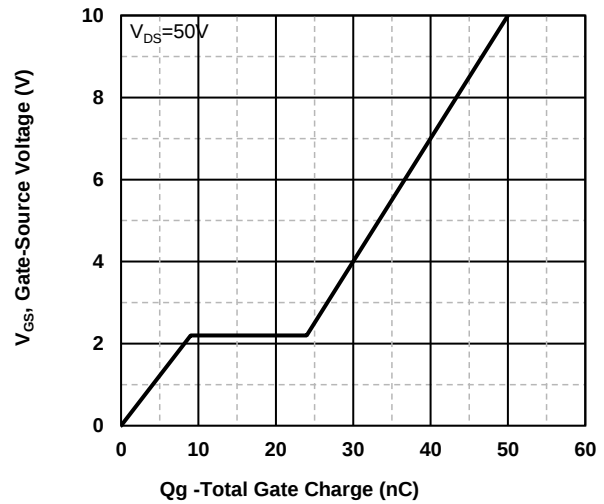
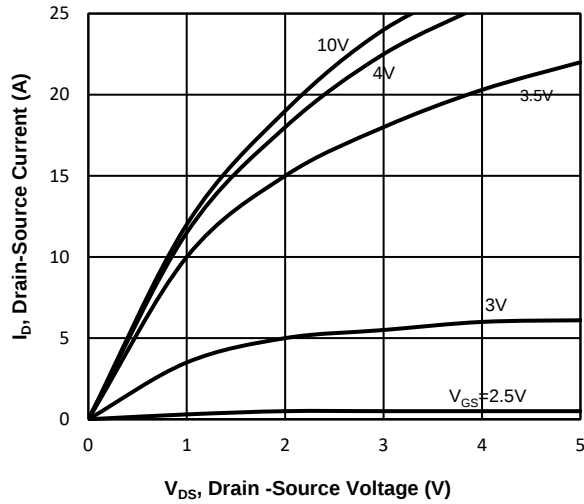
I _{DM}	Pulse Drain Current Tested		60	A
I _b	Continuous Drain Current	Tc=25°C	15	A
P _D	Maximum Power Dissipation	Tc=25°C	50	W
R _{θJA}	Thermal Resistance Junction-Ambient		28	°C/W
E _{AS}	Single pulse Avalanche Energy		18	mJ

Ordering Information (Example)

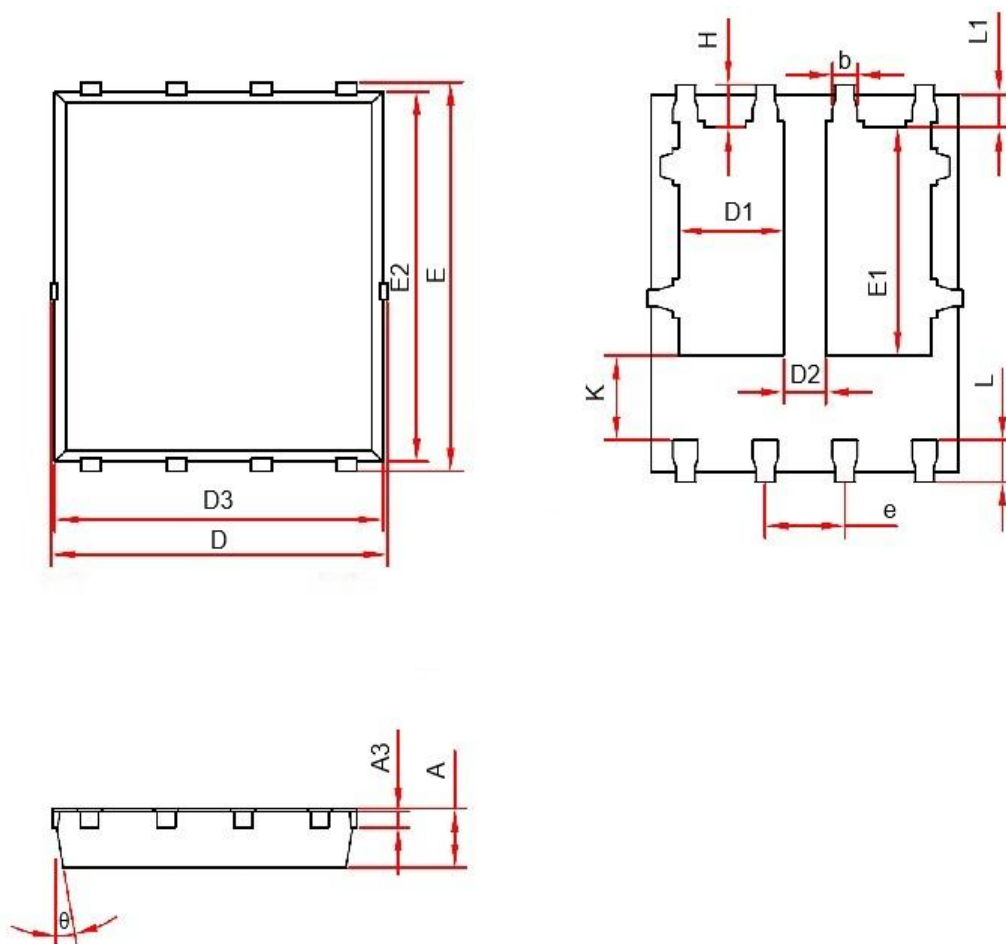
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MCBA15A	PDFN5X6-8L	MCBA15A	5,000	10,000	70,000	13"reel

Electrical Characteristics (T _J =25℃ unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T _J = 25℃ (unless otherwise stated)						
BV _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	100	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =100V, V _{GS} =0V	--	--	1.0	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.0	2	2.5	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =15A	--	75	100	mΩ
		V _{GS} =4.5V, I _D =8A	--	85	120	mΩ
Dynamic Electrical Characteristics @ T _J = 25℃ (unless otherwise stated)						
C _{ISS}	Input Capacitance	V _{DS} =50V, V _{GS} =0V, f=1MHz	--	830	--	pF
C _{OSS}	Output Capacitance		--	44	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	30	--	pF
Switching Characteristics						
Q _g	Total Gate Charge	V _{DD} =50V, I _D =15A, V _{GS} =10V	--	22	--	nC
Q _{gs}	Gate Source Charge		--	2.9	--	nC
Q _{gd}	Gate Drain Charge		--	6.2	--	nC
t _{d(on)}	Turn-on Delay Time	V _{DD} =50V, R _L =6.4Ω, V _{GS} =10V, R _G =3Ω	--	25	--	nS
t _r	Turn-on Rise Time		--	430	--	nS
t _{d(off)}	Turn-Off Delay Time		--	45	--	nS
t _f	Turn-Off Fall Time		--	92	--	nS
Source- Drain Diode Characteristics						
V _{SD}	Forward on voltage	T _J =25℃, I _S =10A	--	--	1.2	V

Typical Operating Characteristics



PDFN5X6-8L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.950	1.050	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.950	5.050	0.196	0.200
E	5.950	6.050	0.235	0.239
D1	1.470	1.870	0.058	0.074
D2	0.470	0.870	0.019	0.034
E1	3.510	3.610	0.139	0.143
D3	4.850	4.950	0.192	0.196
E2	5.700	5.800	0.225	0.229
k	1.190	1.390	0.047	0.055
b	0.300	0.400	0.012	0.016
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
θ	10°	12°	10°	12°